



SANYO Semiconductors

DATA SHEET

FH102A — NPN Epitaxial Planar Silicon Composite Transistor

High-Frequency Low-Noise Amplifier, Differential Amplifier Applications

Features

- Composite type with 2 transistors contained in the MCP package currently in use, improving the mounting efficiency greatly.
- The FH102A is formed with two chips, being equivalent to the 2SC5226A, placed in one package.
- Optimal for differential amplification due to excellent thermal equilibrium and pair capability.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		20	V
Collector-to-Emitter Voltage	V _{CEO}		10	V
Emitter-to-Base Voltage	V _{EBO}		2	V
Collector Current	I _C		70	mA
Collector Dissipation	P _C	When mounted on ceramic substrate (250mm ² ×0.8mm) 1 unit	300	mW
Total Dissipation	P _T	When mounted on ceramic substrate (250mm ² ×0.8mm)	500	mW
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =10V, I _E =0A			1.0	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V, I _C =0A			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =20mA	90		200	

Marking : 102

Continued on next page.

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SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

FH102A

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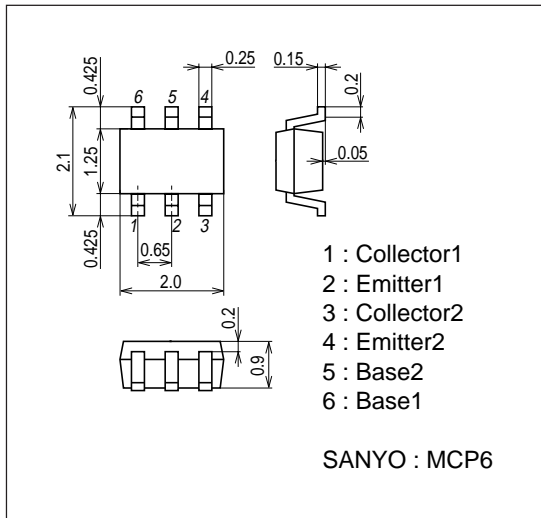
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain Ratio	$h_{FE}(\text{small}/\text{large})$	$V_{CE}=5V, I_C=20mA$	0.7	0.95		
Base-to-Emitter Voltage Difference	$V_{BE}(\text{large}/\text{small})$	$V_{CE}=5V, I_C=20mA$		1.0		mV
Gain-Bandwidth Product	f_T	$V_{CE}=5V, I_C=20mA$	5	7		GHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		0.75	1.2	pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=10V, f=1MHz$		0.5		pF
Forward Transfer Gain	$ S_{21e} ^{21}$	$V_{CE}=5V, I_C=20mA, f=1GHz$	9	12		dB
	$ S_{21e} ^{22}$	$V_{CE}=2V, I_C=3mA, f=1GHz$		8		dB
Noise Figure	NF	$V_{CE}=5V, I_C=7mA, f=1GHz$		1.0	1.8	dB

Note) The specifications shown above are for each individual transistor except the $h_{FE}(\text{small}/\text{large})$ and $V_{BE}(\text{large}/\text{small})$ for which pair capability is also shown.

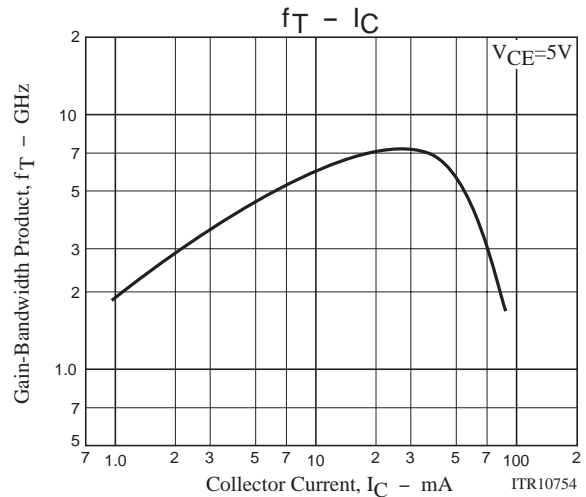
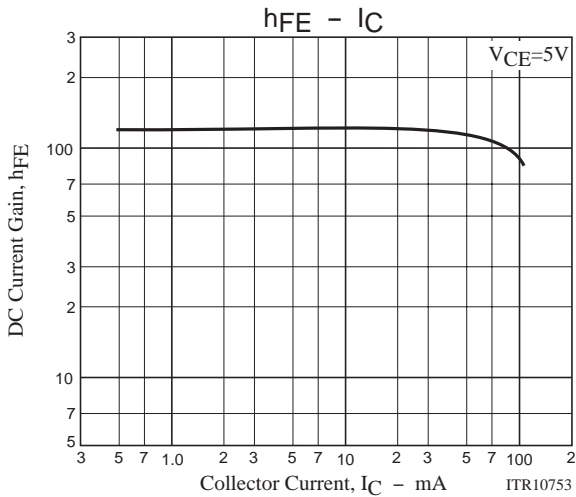
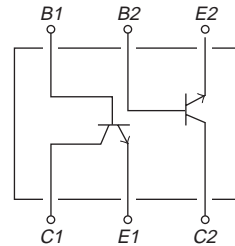
Package Dimensions

unit : mm (typ)

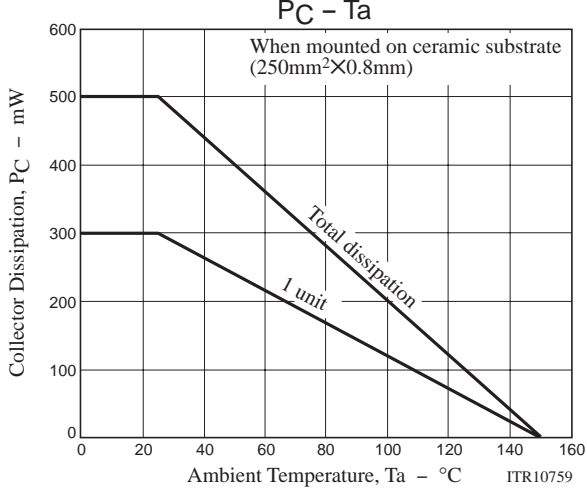
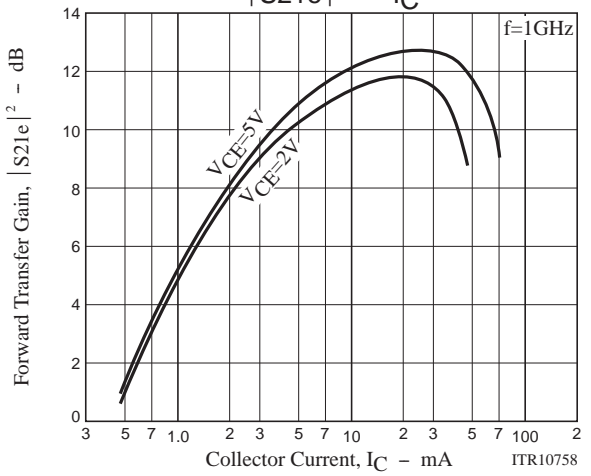
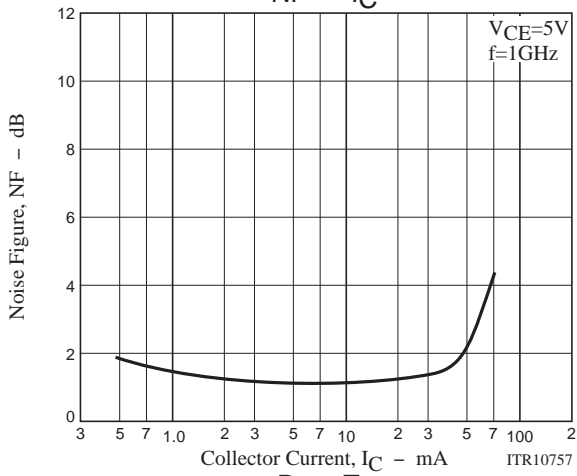
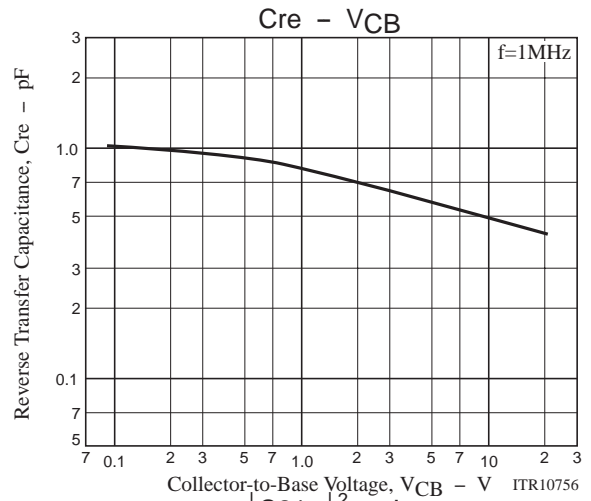
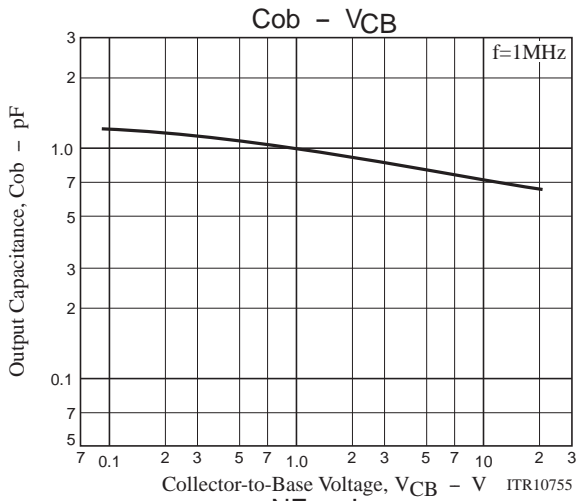
7026-002



Electrical Connection



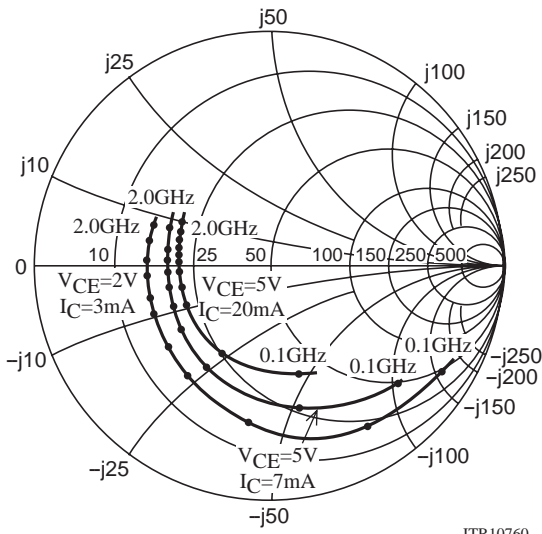
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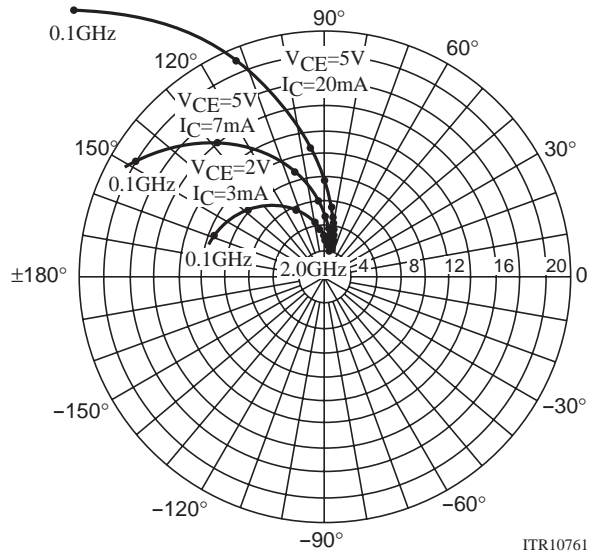
S Parameter

f=100MHz, 200 to 2000MHz(200MHz Step)



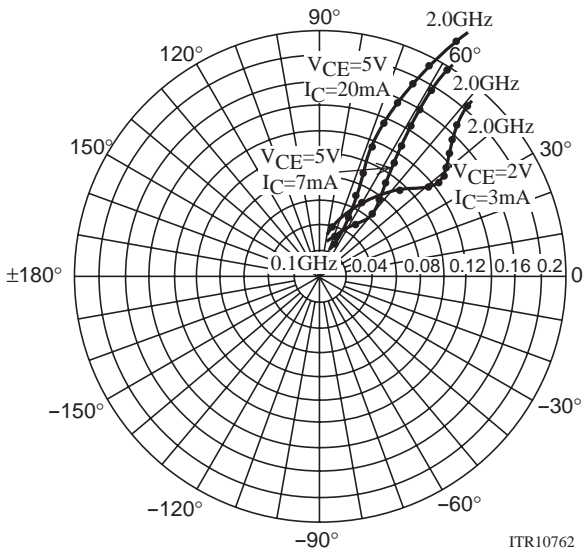
ITR10760

f=100MHz, 200 to 2000MHz(200MHz Step)



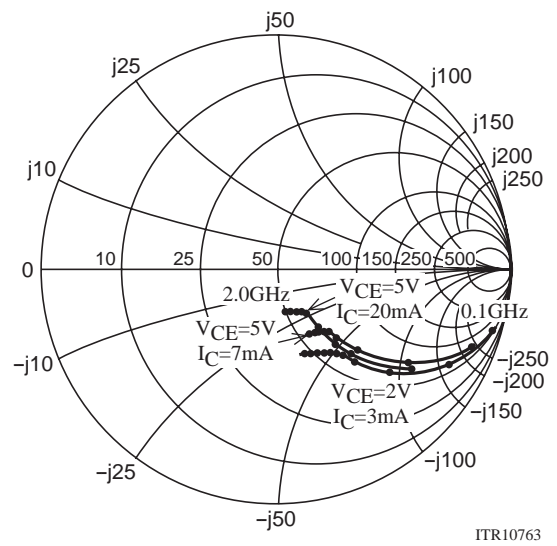
ITR10761

f=100MHz, 200 to 2000MHz(200MHz Step)



ITR10762

f=100MHz, 200 to 2000MHz(200MHz Step)



ITR10763

FH102A

S Parameters (Common emitter)

$V_{CE}=5V, I_C=7mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.720	-46.0	17.973	148.5	0.030	68.5	0.880	-23.6
200	0.612	-80.9	13.927	127.3	0.047	57.1	0.697	-37.6
400	0.497	-121.3	8.656	105.0	0.066	51.3	0.479	-47.6
600	0.456	-143.5	6.080	92.8	0.079	52.9	0.382	-50.5
800	0.440	-157.6	4.725	84.3	0.094	55.4	0.339	-51.8
1000	0.436	-167.5	3.864	77.0	0.110	56.8	0.323	-53.4
1200	0.434	-176.1	3.258	70.3	0.126	57.9	0.312	-55.8
1400	0.433	176.6	2.847	64.5	0.143	58.4	0.304	-58.3
1600	0.433	170.9	2.329	57.4	0.160	58.9	0.296	-62.0
1800	0.434	165.0	2.252	54.2	0.178	58.6	0.293	-65.0
2000	0.439	159.6	2.057	49.2	0.197	58.1	0.294	-68.1

$V_{CE}=5V, I_C=20mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.481	-78.8	29.795	132.9	0.022	63.9	0.707	-38.2
200	0.420	-119.2	19.008	112.2	0.033	60.8	0.470	-51.1
400	0.391	-151.6	10.416	95.4	0.052	64.7	0.296	-55.3
600	0.386	-166.4	7.084	86.6	0.071	67.2	0.236	-56.1
800	0.381	-175.9	5.407	80.1	0.092	68.4	0.213	-56.6
1000	0.382	178.2	4.401	74.1	0.114	67.8	0.208	-57.9
1200	0.385	172.1	3.701	68.5	0.134	66.8	0.204	-60.7
1400	0.388	166.7	3.217	63.6	0.156	65.6	0.202	-63.5
1600	0.390	162.1	2.839	58.8	0.176	64.0	0.199	-67.9
1800	0.391	156.7	2.534	54.3	0.197	62.4	0.197	-71.2
2000	0.394	152.1	2.319	50.1	0.219	60.6	0.197	-74.2

$V_{CE}=2V, I_C=3mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.858	-32.4	9.413	157.2	0.040	72.6	0.945	-16.5
200	0.782	-60.7	8.187	138.5	0.070	59.2	0.833	-29.3
400	0.653	-101.1	5.855	113.8	0.101	44.5	0.637	-43.2
600	0.588	-126.5	4.337	98.4	0.114	39.1	0.515	-50.0
800	0.557	-143.7	3.444	87.7	0.122	38.0	0.454	-53.8
1000	0.543	-156.3	2.871	78.5	0.130	38.6	0.426	-57.1
1200	0.536	-166.8	2.446	70.5	0.137	40.3	0.407	-60.3
1400	0.533	-175.5	2.145	63.5	0.146	42.5	0.393	-63.8
1600	0.527	177.0	1.904	57.1	0.155	45.0	0.382	-68.0
1800	0.525	170.3	1.714	51.7	0.168	47.3	0.379	-72.0
2000	0.528	163.8	1.564	45.9	0.183	49.2	0.378	-75.8

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